

8085AH/8085AH-2/8085AH-1 8-BIT HMOS MICROPROCESSORS

- Single +5V Power Supply with 10% Voltage Margins
- 3 MHz, 5 MHz and 6 MHz Selections Available
- 20% Lower Power Consumption than 8085A for 3 MHz and 5 MHz
- 1.3 μs Instruction Cycle (8085AH); 0.8 μs (8085AH-2); 0.67 μs (8085AH-1)
- 100% Software Compatible with 8080A
- On-Chip Clock Generator (with External Crystal, LC or RC Network)

- On-Chip System Controller; Advanced Cycle Status Information Available for Large System Control
- Four Vectored Interrupt Inputs (One Is Non-Maskable) Plus an 8080A-Compatible Interrupt
- Serial in/Serial Out Port
- Decimal, Binary and Double Precision Arithmetic
- Direct Addressing Capability to 64K
 Bytes of Memory
- Available in 40-Lead Cerdip and Plastic Packages

The 8085AH is a complete 8-bit parallel Central Processing Unit (CPU) implemented in N-channel, depletion load, silicon gate technology (HMOS). Its instruction set is 100% software compatible with the 8080A microprocessor, and it is designed to improve the present 8080A's performance by higher system speed. Its high level of system integration allows a minimum system of three IC's [8085AH (CPU), 8156H (RAM/IO) and 8755A (EPROM/IO)] while maintaining total system expandability. The 8085AH-2 and 8085AH-1 are faster versions of the 8085AH.

The 8085AH incorporates all of the features that the 8224 (clock generator) and 8228 (system controller) provided for the 8080A, thereby offering a higher level of system integration.

The 8085AH uses a multiplexed data bus. The address is split between the 8-bit address bus and the 8-bit data bus. The on-chip address latches of 8155H/8156H/8755A memory products allow a direct interface with the 8085AH.

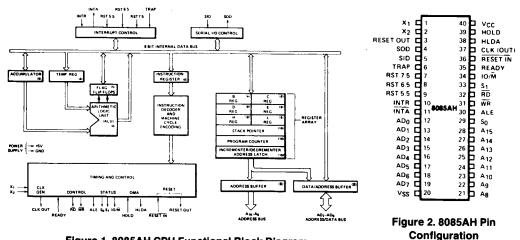


Figure 1. 8085AH CPU Functional Block Diagram

For complete Rochester ordering guide, please refer to page 2
Please contact factory for specific package availability and
Military/Aerospace specifications/availability.

Rochester Electronics guarantees performance of its semiconductor products to the original OEM specifications. "Typical" values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing. Rochester Electronics reserves the right to make changes without further notice to any specification herein.

8085AH/-1/-2

Rochester Ordering Guide

*Most products can also be offered as RoHS compliant, designated by a –G suffix. Please contact factory for more information.

Rochester Part Number	Intel Part Number	Package	Temperature
D8085AH	D8085AH	CDIP-40	0° to +70°C
D8085AH-1	D8085AH-1	CDIP-40	0° to +70°C
D8085AH-2	D8085AH-2	CDIP-40	0° to +70°C
P8085AH	P8085AH	PDIP-40	0° to +70°C
P8085AH-1	P8085AH-1	PDIP-40	0° to +70°C
P8085AH-2	P8085AH-2	PDIP-40	0° to +70°C
QD8085AH	QD8085AH	CDIP-40	0° to +70°C
QD8085AH-2	QD8085AH-2	CDIP-40	0° to +70°C
QP8085AH	QP8085AH	PDIP-40	0° to +70°C
QP8085AH-2	QP8085AH-2	PDIP-40	0° to +70°C

Table 1. Pin Description

Symbol	Туре	Name and Function
A ₈ -A ₁₅	0	ADDRESS BUS: The most significant 8 bits of memory address or the 8 bits of the I/O address, 3-stated during Hold and Halt modes and during RESET.
AD ₀₋₇	1/0	MULTIPLEXED ADDRESS/DATA BUS: Lower 8 bits of the memory address (or I/O address) appear on the bus during the first clock cycle (T state) of a machine cycle. It then becomes the data bus during the second and third clock cycles.
ALE	O	ADDRESS LATCH ENABLE: It occurs during the first clock state of a machine cycle and enables the address to get latched into the on-chip latch of peripherals. The falling edge of ALE is set to guarantee setup and hold times for the address information. The falling edge of ALE can also be used to strobe the status information. ALE is never 3-stated.
S_0 , S_1 and IO/\overline{M}	0	MACHINE CYCLE STATUS:
		IO/M S ₁ S ₀ Status 0 0 1 Memory write 0 1 0 Memory read 1 0 1 I/O write 1 1 0 I/O read 0 1 1 Opcode fetch 1 1 1 Interrupt Acknowledge * 0 0 Halt * X X Hold * X X Reset * = 3-state (high impedance) X = unspecified S ₁ can be used as an advanced R/W status. IO/M, S ₀ and S ₁ become valid at the beginning of a machine cycle and remain stable throughout the cycle. The falling edge of ALE may be used to latch the state of these lines.
RD	0	READ CONTROL: A low level on $\overline{\text{RD}}$ indicates the selected memory or I/O device is to be read and that the Data Bus is available for the data transfer, 3-stated during Hold and Halt modes and during RESET.
WR	0	WROTE CONTROL: A low level on WR indicates the data on the Data Bus is to be written into the selected memory or I/O location. Data is set up at the trailing edge of WR. 3-stated during Hold and Halt modes and during RESET.
READY	-	READY: If READY is high during a read or write cycle, it indicates that the memory or peripheral is ready to send or receive data. If READY is low, the CPU will wait an integral number of clock cycles for READY to go high before completing the read or write cycle. READY must conform to specified setup and hold times.
HOLD	ì	HOLD: Indicates that another master is requesting the use of the address and data buses. The CPU, upon receiving the hold request, will relinquish the use of the bus as soon as the completion of the current bus transfer. Internal processing can continue. The processor can regain the bus only after the HOLD is removed. When the HOLD is acknowledged, the Address, Data RD, WR, and IO/M lines are 3-stated.
HLDA	0	HOLD ACKNOWLEDGE: Indicates that the CPU has received the HOLD request and that it will relinquish the bus in the next clock cycle. HILDA goes low after the Hold request is removed. The CPU takes the bus one half clock cycle after HLDA goes low.
INTR		INTERRUPT REQUEST: Is used as a general purpose interrupt. It is sampled only during the next to the last clock cycle of an instruction and during Hold and Halt states. If it is active, the Program Counter (PC) will be inhibited from incrementing and an INTA will be issued. During this cycle a RESTART or CALL instruction can be inserted to jump to the interrupt service routine. The INTR is enabled and disabled by software. It is disabled by Reset and immediately after an interrupt is accepted.

Table 1. Pin Description (Continued)

Symbol	Туре	Name and Function
INTA	0	INTERRUPT ACKNOWLEDGE: Is used instead of (and has the same timing as) RD during the Instruction cycle after an INTR is accepted. It can be used to activate an 8259A Interrupt chip or some other interrupt port.
RST 5.5 RST 6.5	1	RESTART INTERRUPTS: These three inputs have the same timing as INTR except they cause an internal RESTART to be automatically inserted.
RST 7.5		The priority of these interrupt is ordered as shown in Table 2. These interrupts have a higher priority than INTR. In addition, they may be individually masked out using the SIM instruction.
TRAP	ı	TRAP: Trap interrupt is a non-maskable RESTART interrupt. It is recognized at the same time as INTR or RST 5.5–7.5. It is unaffected by any mask or Interrupt Enable. It has the highest priority of any interrupt. (See Table 2.)
RESETIN	1	RESET IN: Sets the Program Counter to zero and resets the Interrupt Enable and HLDA flip-flops. The data and address buses and the control lines are 3-stated during RESET and because of the asynchronous nature of RESET, the processor's internal registers and flags may be altered by RESET with unpredictable results. RESET IN is a Schmitt-triggered input, allowing connection to an R-C network for power-on RESET delay (see Figure 3). Upon power-up, RESET IN must remain low for at least 10 ms after minimum V _{CC} has been reached. For proper reset operation after the power-up duration, RESET IN should be kept low a minimum of three clock periods. The CPU is held in the reset condition as long as RESET IN is applied.
RESET OUT	0	RESET OUT: Reset Out indicates CPU is being reset. Can be used as a system reset. The signal is synchronized to the processor clock and lasts an integral number of clock periods.
X ₁ , X ₂		X_1 and X_2 : Are connected to a crystal, LC, or RC network to drive the internal clock generator. X_1 can also be an external clock input from a logic gate. The input frequency is divided by 2 to give the processor's internal operating frequency.
CLK	0	CLOCK: Clock output for use as a system clock. The period of CLK is twice the X_1 , X_2 input period.
SID	l	SERIAL INPUT DATA LINE: The data on this line is loaded into accumulator bit 7 whenever a RIM instruction is executed.
SOD	0	SERIAL OUTPUT DATA LINE: The output SOD is set or reset as specified by the SIM instruction.
V _{CC}		POWER: +5 volt supply.
V _{SS}		GROUND: Reference.

Table 2. Interrupt Priority, Restart Address and Sensitivity

Name	Priority	Address Branched to ⁽¹⁾ When Interrupt Occurs	Type Trigger			
TRAP	1	24H	Rising Edge AND High Level until Sampled			
RST 7.5	2	3CH	Rising Edge (Latched)			
RST 6.5	3	34H	High Level until Sampled			
RST 5.5	ST 5.5 4 2CH		High Level until Sampled			
INTR	5	(Note 2)	High Level until Sampled			

The processor pushes the PC on the stack before branching to the indicated address.
 The address branched to depends on the instruction provided to the CPU when the interrupt is acknowledged.

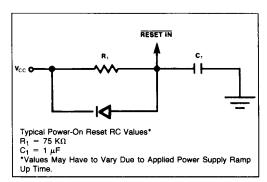


Figure 3. Power-On Reset Circuit

FUNCTIONAL DESCRIPTION

The 8085AH is a complete 8-bit parallel central processor. It is designed with N-channel, depletion load, silicon gate technology (HMOS), and requires a single +5V supply. Its basic clock speed is 3 MHz (8085AH), 5 MHz (8085AH-2), or 6 MHz (8085-AH-1), thus improving on the present 8080A's performance with higher system speed. Also it is designed to fit into a minimum system of three IC's: The CPU (8085AH), a RAM/IO (8156H), and an EPROM/IO chip (8755A).

The 8085AH has twelve addressable 8-bit registers. Four of them can function only as two 16-bit register pairs. Six others can be used interchangeably as 8-bit registers or as 16-bit register pairs. The 8085AH register set is as follows:

OUUSAITIUG	istoi set is as iono	W3.
Mnemonic	Register	Contents
ACC or A	Accumulator	8 Bits
PC	Program Counter	16-Bit Address
BC, DE, HL	General-Purpose	8-Bits x 6 or
	Registers; data pointer (HL)	16 Bits x 3
SP	Stack Pointer	16-Bit Address
Flags or F	Flag Register	5 Flags (8-Bit Space)

The 8085AH uses a multiplexed Data Bus. The address is split between the higher 8-bit Address Bus and the lower 8-bit Address/Data Bus. During the first T state (clock cycle) of a machine cycle the low order address is sent out on the Address/Data bus. These lower 8 bits may be latched externally by the Address Latch Enable signal (ALE). During the rest of the machine cycle the data bus is used for memory or I/O data.

The 8085AH provides $\overline{\text{RD}}$, $\overline{\text{WR}}$, S_0 , S_1 , and $IO/\overline{\text{M}}$ signals for bus control. An Interrupt Acknowledge signal ($\overline{\text{INTA}}$) is also provided. HOLD and all Interrupts are synchronized with the processor's internal clock. The 8085AH also provides Serial Input Data

(SID) and Serial Output Data (SOD) lines for simple serial interface.

In addition to these features, the 8085AH has three maskable, vector interrupt pins, one nonmaskable TRAP interrupt, and a bus vectored interrupt, INTR.

INTERRUPT AND SERIAL I/O

The 8085AH has 5 interrupt inputs: INTR, RST 5.5, RST 6.5, RST 7.5, and TRAP. INTR is identical in function to the 8080A INT. Each of the three RE-START inputs, 5.5, 6.5, and 7.5, has a programmable mask. TRAP is also a RESTART interrupt but it is nonmaskable.

The three maskable interrupt cause the internal execution of RESTART (saving the program counter in the stack and branching to the RESTART address) if the interrupts are enabled and if the interrupt mask is not set. The nonmaskable TRAP causes the internal execution of a RESTART vector independent of the state of the interrupt enable or masks. (See Table 2.)

There are two different types of inputs in the restart interrupts. RST 5.5 and RST 6.5 are *high level-sensitive* like INTR (and INT on the 8080) and are recognized with the same timing as INTR. RST 7.5 is *rising edge-sensitive*.

For RST 7.5, only a pulse is required to set an internal flip-flop which generates the internal interrupt request (a normally high level signal with a low going pulse is recommended for highest system noise immunity). The RST 7.5 request flip-flop remains set until the request is serviced. Then it is reset automatically. This flip-flop may also be reset by using the SIM instruction or by issuing a RESET IN to the 8085AH. The RST 7.5 internal flip-flop will be set by a pulse on the RST 7.5 pin even when the RST 7.5 interrupt is masked out.

The status of the three RST interrupt masks can only be affected by the SIM instruction and RESET IN. (See SIM, Chapter 5 of the 8080/8085 User's Manual.)

The interrupts are arranged in a fixed priority that determines which interrupt is to be recognized if more than one is pending as follows: TRAP—highest priority, RST 7.5, RST 6.5, RST 5.5, INTR—lowest priority. This priority scheme does not take into account the priority of a routine that was started by a higher priority interrupt. RST 5.5 can interrupt an RST 7.5 routine if the interrupts are re-enabled before the end of the RST 7.5 routine.

The TRAP interrupt is useful for catastrophic events such as power failure or bus error. The TRAP input is recognized just as any other interrupt but has the

highest priority. It is not affected by any flag or mask. The TRAP input is both *edge and level sensitive*. The TRAP input must go high and remain high until it is acknowledged. It will not be recognized again until it goes low, then high again. This avoids any false triggering due to noise or logic glitches. Figure 4 illustrates the TRAP interrupt request circuitry within the 8085AH. Note that the servicing of any interrupt (TRAP, RST 7.5, RST 6.5, RST 5.5, INTR) disables all future interrupts (except TRAPs) until an El instruction is executed.

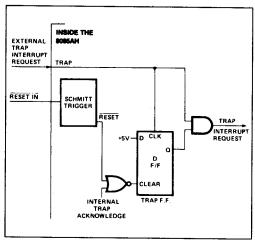


Figure 4. TRAP and RESET In Circuit

The TRAP interrupt is special in that it disables interrupts, but preserves the previous interrupt enable status. Performing the first RIM instruction following a TRAP interrupt allows you to determine whether interrupts were enabled or disabled prior to the TRAP. All subsequent RIM instructions provide current interrupt enable status. Performing a RIM instruction following INTR, or RST 5.5-7.5 will provide current Interrupt Enable status, revealing that interrupts are disabled. See the description of the RIM instruction in the 8080/8085 Family User's Manual.

The serial I/O system is also controlled by the RIM and SIM instruction. SID is read by RIM, and SIM sets the SOD data.

DRIVING THE X1 AND X2 INPUTS

You may drive the clock inputs of the 8085AH, 8085AH-2, or 8085AH-1 with a crystal, an LC tuned circuit, an RC network, or an external clock source. The crystal frequency must be at least 1 MHz, and must be twice the desired internal clock frequency;

hence, the 8085AH is operated with a 6 MHz crystal (for 3 MHz clock), the 8085AH-2 operated with a 10 MHz crystal (for 5 MHz clock), and the 8085AH-1 can be operated with a 12 MHz crystal (for 6 MHz clock). If a crystal is used, it must have the following characteristics:

Parallel resonance at twice the clock frequency desired

 C_L (load capacitance) \leq 30 pF C_S (Shunt capacitance) \leq 7 pF

 R_S (equivalent shunt resistance) $\leq 75\Omega$

Drive level: 10 mW

Frequency tolerance: ±0.005% (suggested)

Note the use of the 20 pF capacitor between $\rm X_2$ and ground. This capacitor is required with crystal frequencies below 4 MHz to assure oscillator startup at the correct frequency. A parallel-resonant LC citcuit may be used as the frequency-determining network for the 8085AH, providing that its frequency tolerance of approximately \pm 10% is acceptable. The components are chosen from the formula:

$$f = \frac{1}{2\pi\sqrt{L(C_{ext} + C_{int})}}$$

To minimize variations in frequency, it is recommended that you choose a value for C_{ext} that is at least twice that of C_{int}, or 30 pF. The use of an LC circuit is not recommended for frequencies higher than approximately 5 MHz.

An RC circuit may be used as the frequency-determining network for the 8085AH if maintaining a precise clock frequency is of no importance. Variations in the on-chip timing generation can cause a wide variation in frequency when using the RC mode. Its advantage is its low component cost. The driving frequency generated by the circuit shown is approximately 3 MHz. It is not recommended that frequencies greatly higher or lower than this be attempted.

Figure 5 shows the recommended clock driver circuits. Note in d and e that pullup resistors are required to assure that the high level voltage of the input is at least 4V and maximum low level voltage of 0.8V.

For driving frequencies up to and including 6 MHz you may supply the driving signal to X_1 and leave X_2 open-circuited (Figure 5d). If the driving frequency is from 6 MHz to 12 MHz, stability of the clock generator will be improved by driving both X_1 and X_2 with a push-pull source (Figure 5e). To prevent self-oscillation of the 8085AH, be sure that X_2 is not coupled back to X_1 through the driving circuit.

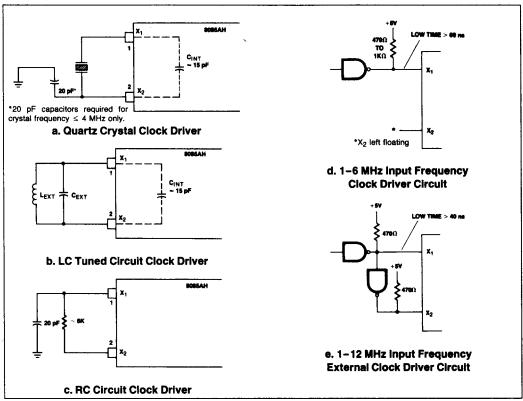


Figure 5. Clock Driver Circuits

GENERATING AN 8085AH WAIT STATE

If your system requirements are such that slow memories or peripheral devices are being used, the circuit shown in Figure 6 may be used to insert one WAIT state in each 8085AH machine cycle.

The D flip-flops should be chosen so that

- CLK is rising edge-triggered
- CLEAR is low-level active.

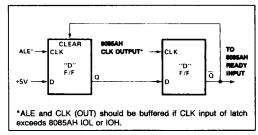


Figure 6. Generation of a Wait State for 8085AH CPU

As in the 8080, the READY line is used to extend the read and write pulse lengths so that the 8085AH can be used with slow memory. HOLD causes the CPU to relinquish the bus when it is through with it by floating the Address and Data Buses.

SYSTEM INTERFACE

The 8085AH family includes memory components, which are directly compatible to the 8085AH CPU. For example, a system consisting of the three chips, 8085AH, 8156H and 8755A will have the following features:

- 2K Bytes EPROM
- 256 Bytes RAM
- 1 Timer/Counter
- 4 8-bit I/O Ports
- 1 6-bit I/O Port
- 4 Interrupt Levels
- · Serial In/Serial Out Ports

This minimum system, using the standard I/O technique is as shown in Figure 7.

In addition to the standard I/O, the memory mapped I/O offers an efficient I/O addressing technique. With this technique, an area of memory address space is assigned for I/O address, thereby, using the memory address for I/O manipulation. Figure 8

shows the system configuration of Memory Mapped I/O using 8085AH.

The 8085AH CPU can also interface with the standard memory that does *not* have the multiplexed address/data bus. It will require a simple 8-bit latch as shown in Figure 9.

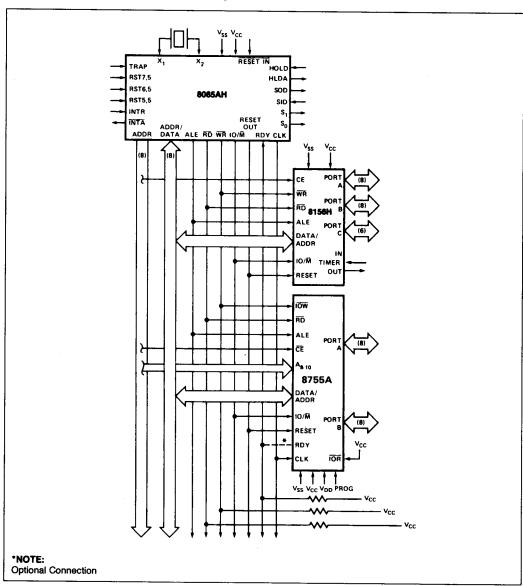


Figure 7. 8085AH Minimum System (Standard I/O Technique)

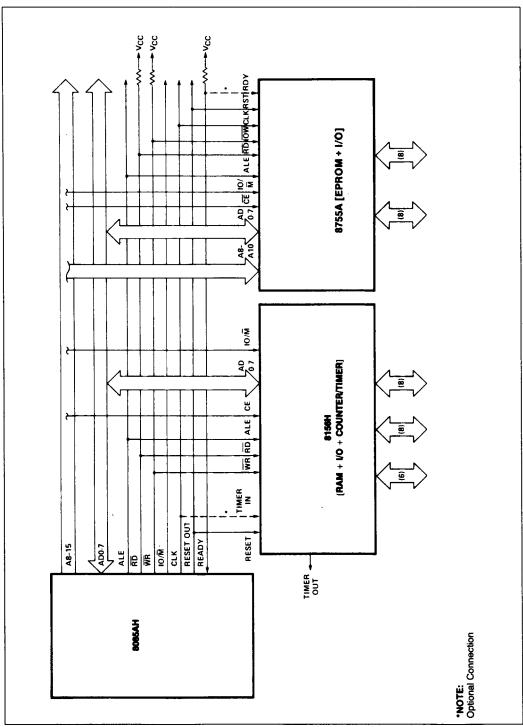


Figure 8. 8085 Minimum System (Memory Mapped I/O)

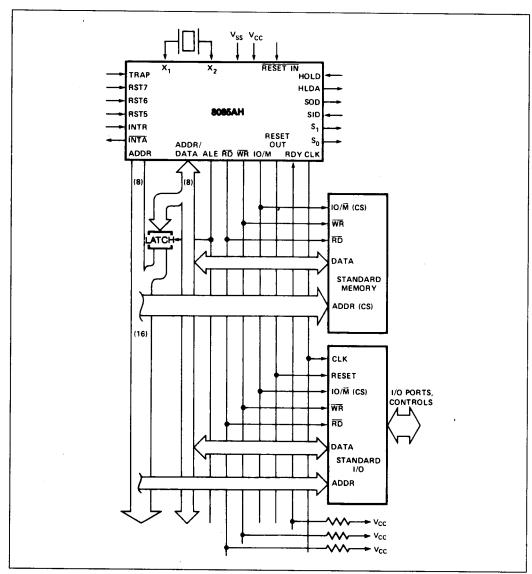


Figure 9. 8085 System (Using Standard Memories)

BASIC SYSTEM TIMING

The 8085AH has a multiplexed Data Bus. ALE is used as a strobe to sample the lower 8-bits of address on the Data Bus. Figure 10 shows an instruction fetch, memory read and I/O write cycle (as would occur during processing of the OUT instruction). Note that during the I/O write and read cycle that the I/O port address is copied on both the upper and lower half of the address.

There are seven possible types of machine cycles. Which of these seven takes place is defined by the status of the three status lines (IO/\overline{M} , S_1 , S_0) and

the three control signals (\overline{RD} , \overline{WR} , and \overline{INTA}). (See Table 3.) The status lines can be used as advanced controls (for device selection, for example), since they become active at the T_1 state, at the outset of each machine cycle. Control lines \overline{RD} and \overline{WR} become active later, at the time when the transfer of data is to take place, so are used as command lines.

A machine cycle normally consists of three T states, with the exception of OPCODE FETCH, which normally has either four or six T states (unless WAIT or HOLD states are forced by the receipt of READY or HOLD inputs). Any T state must be one of ten possible states, shown in Table 4.

Table 3. 8085AH Machine Cycle Chart

Machine Cycle			St	atus		Control			
			IO/M	S1	SO	RD	WR	INTA	
OPCODE FETCH	(OF)		0	1	1	0	1	1	
MEMORY READ	(MR)		0	1	0	0	1	1	
MEMORY WRITE	(MW)		0	0	1	1	0	1	
I/O READ	(IOR)		1	1	0	0	1	1	
I/O WRITE	(IOW)		1	0	1	1	0	1	
ACKNOWLEDGE OF INTR	(INA)		1	1	1	1	1	0	
BUS IDLE	(BI):	DAD ACK.OF	0	1	0	1	1	1	
		RST,TRAP	1	1	1	1	1	1	
		HALT	TS	0	0	TS	TS	1	

Table 4. 8085AH Machine State Chart

Machine		С	ontrol				
State	S1,S0	IO/M	A ₈ -A ₁₅	RD, WR	INTA	ALE	
T ₁	х	Х	X	Х	1	1	1*
T ₂	×	Х	X	Х	Х	Х	0
T _{WAIT}	×	Х	Х	Х	Х	Х	0
T ₃	×	Х	х	Х	Х	х	0
T ₄	1	0†	Х	TS	1	1	0
T ₅	1	0†	Х	TS	1	1	0
Т ₆	1	0†	Х	TS	1	1	0
TRESET	X	TS	TS	TS	TS	1	0
T _{HALT}	0	TS	TS	TS	TS	1	0
THOLD	, X	TS	TS	TS	TS	1	0

^{0 =} Logic "0" 1 = Logic "1"

TS = High Impedance

Logic "1" X = Unspecified

^{*}ALE not generated during 2nd and 3rd machine cycles of DAD instruction.

 $[\]dagger IO/\overline{M} = 1$ during $T_4 - T_6$ of INA machine cycle.

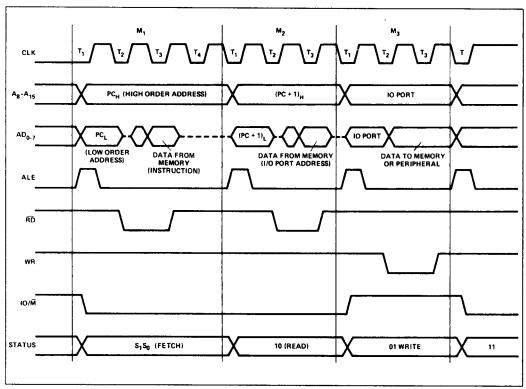


Figure 10. 8085AH Basic System Timing

ABSOLUTE MAXIMUM RATINGS*

Ambient Temperature under Bias0°C to 70°C Storage Temperature-65°C to +150°C Voltage on Any Pin with Respect to Ground-0.5V to +7V Power Dissipation1.5W

NOTICE: This is a production data sheet. The specifications are subject to change without notice.

*WARNING: Stressing the device beyond the "Absolute Maximum Ratings" may cause permanent damage. These are stress ratings only. Operation beyond the "Operating Conditions" is not recommended and extended exposure beyond the "Operating Conditions" may affect device reliability.

D.C. CHARACTERISTICS

8085AH, 8085AH-2: $T_A=0^\circ\text{C}$ to 70°C, $V_{CC}=5\text{V}\pm10\%$, $V_{SS}=0\text{V}$; unless otherwise specified* 8085AH-1: $T_A=0^\circ\text{C}$ to 70°C, $V_{CC}=5\text{V}\pm5\%$, $V_{SS}=0\text{V}$; unless otherwise specified*

Symbol	Parameter	Min	Max	Units	Test Conditions
V _{IL}	Input Low Voltage	-0.5	+0.8	V	
V _{IH}	Input High Voltage	2.0	V _{CC} + 0.5	٧	
V _{OL}	Output Low Voltage		0.45	V	I _{OL} = 2 mA
V _{OH}	Output High Voltage	2.4		V	I _{OH} = -400 μA
lcc	Power Supply Current		135	mA	8085AH, 8085AH-2
			200	mA	8085AH-1
կլ	Input Leakage		±10	μА	0 ≤ V _{IN} ≤ V _{CC}
I _{LO}	Output Leakage		±10	μΑ	0.45V ≤ V _{OUT} ≤ V _{CC}
VILR	Input Low Level, RESET	-0.5	+0.8	٧	
V _{IHR}	Input High Level, RESET	2.4	V _{CC} + 0.5	٧	
V _{HY}	Hysteresis, RESET	0.15		V	

A.C. CHARACTERISTICS

8085AH, 8085AH-2: $T_A = 0^{\circ}$ C to 70°C, $V_{CC} = 5$ V $\pm 10\%$, $V_{SS} = 0$ V* 8085AH-1: $T_A = 0^{\circ}$ C to 70°C, $V_{CC} = 5$ V $\pm 5\%$, $V_{SS} = 0$ V

Symbol	Parameter	8085	AH (2)	8085 <i>A</i>	H-2 (2)	8085A	Units	
	- arameter	Min	Max	Min	Max	Min	Max	Uiiila
tcyc	CLK Cycle Period	320	2000	200	2000	167	2000	ns
t ₁	CLK Low Time (Standard CLK Loading)	80		40		20		ns
t ₂	CLK High Time (Standard CLK Loading)	120		70		50		ns
t _r , t _f	CLK Rise and Fall Time		30		30		30	ns
t _{XKR}	X ₁ Rising to CLK Rising	20	120	20	100	20	100	ns
t _{XKF}	X ₁ Rising to CLK Falling	20	150	20	110	20	110	ns
t _{AC}	A ₈₋₁₅ Valid to Leading Edge of Control (1)	270		115		70		ns
tACL	A ₀₋₇ Valid to Leading Edge of Control	240		115		60		ns
t _{AD}	A ₀₋₁₅ Valid to Valid Data In		575		350		225	ns
t _{AFR}	Address Float after Leading Edge of READ (INTA)		0		0		0	ns
t _{AL}	A ₈₋₁₅ Valid before Trailing Edge of ALE (1)	115		50		25		ns

*NOTE:

For Extended Temperature EXPRESS use M8085AH Electricals Parameters.

A.C. CHARACTERISTICS (Continued)

Symbol	Parameter	8085	AH (2)	8085A	H-2 (2)	8085A	Units	
	T diameter	Min	Max	Min	Max	Min	Max	Units
t _{ALL}	A ₀₋₇ Valid before Trailing Edge of ALE	90		50		25		ns
tary	READY Valid from Address Valid		220		100		40	ns
t _{CA}	Address (A ₈₋₁₅) Valid after Control	120		60		30		ns
tcc	Width of Control Low (RD, WR, INTA) Edge of ALE	400		230		150		ns
^t CL	Trailing Edge of Control to Leading Edge of ALE	50		25		0		ns
t _{DW}	Data Valid to Trialing Edge of WRITE	420		230		140		ns
t _{HABE}	HLDA to Bus Enable	-	210		150		150	ns
tHABF	Bus Float after HLDA		210	-	150		150	ns
t _{HACK}	HLDA Valid to Trailing Edge of CLK	110		40		0		ns
^t HDH	HOLD Hold Time	0		0		0		ns
t _{HDS}	HOLD Setup Time to Trailing Edge of CLK	170		120		120		ns
tinh	INTR Hold Time	0		0		0		ns
tins	INTR, RST, and TRAP Setup Time to Falling Edge of CLK			150		150	-	ns
t_{LA}	Address Hold Time after ALE	100		50		20		ns
t _{LC}	Trailing Edge of ALE to Leading Edge of Control	130		60		25		ns
tLCK	ALE Low During CLK High	100		50		15		ns
t _{LDR}	ALE to Valid Data during Read		460		270		175	ns
t _{LDW}	ALE to Valid Data during Write		200		140		110	ns
t _{LL}	ALE Width	140		80		50		ns
t _{LRY}	ALE to READY Stable		110		30		10	ns
t _{RAE}	Trailing Edge of READ to Re-Enabling of Address	150		90		50		ns
t _{RD}	READ (or INTA) to Valid Data		300		150		75	ns
t _{RV}	Control Trailing Edge to Leading Edge of Next Control	400		220		160		ns
t _{RDH}	Data Hold Time after READ INTA	0		0		0		ns
t _{RYH}	READY Hold Time	0		0		5		ns
t _{RYS}	READY Setup Time to Leading Edge of CLK			100		100		ns
t _{WD}	Data Valid after Trailing Edge of WRITE	100		60		30		ns
t _{WDL}	LEADING Edge of WRITE to Data Valid		40		20		30	ns

NOTES:

1. A₈-A₁₅ address Specs apply IO/M̄, S₀, and S₁ except A₈-A₁₅ are undefined during T₄-T₆ of OF cycle whereas IO/M̄, S₀, and S₁ are stable.

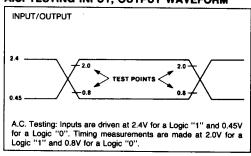
2. *Test Conditions*: t_{CYC} = 320 ns (8085AH)/200 ns (8085AH-2);/167 ns (8085AH-1); C_L = 150 pF.

3. For all output timing where C ≠ 150 pF use the following correction factors: 25 pF ≤ C_L < 150 pF: −0.10 ns/pF 150 pF < C_L ≤ 300 pF: +0.30 ns/pF

4. Output timings are measured with purely capacitive load.

5. To calculate timing specifications at other values of t_{CYC} use Table 5.

A.C. TESTING INPUT, OUTPUT WAVEFORM



A.C. TESTING LOAD CIRCUIT

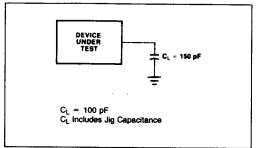


Table 5. Bus Timing Specification as a T_{CYC} Dependent

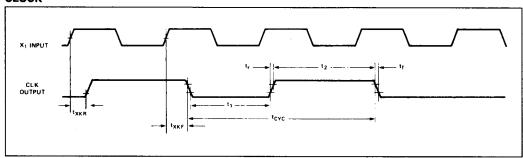
Symbol	8085AH	8085AH-2	8085AH-1	
t _{AL}	(1/2)T - 45	(1/2)T - 50	(1/2)T - 58	Minimum
t _{LA}	(1/2)T - 60	(1/2)T - 50	(1/2)T 63	Minimum
tլլ	(1/2)T - 20	(1/2)T — 20	(1/2)T - 33	Minimum
t _{LCK}	(1/2)T - 60	(1/2)T - 50	(1/2)T - 68	Minimum
tLC	(1/2)T - 30	(1/2)T - 40	(1/2)T - 58	Minimum
t _{AD}	(5/2 + N)T - 225	(5/2 + N)T - 150	(5/2 + N)T - 192	Maximum
t _{RD}	(3/2 + N)T - 180	(3/2 + N)T - 150	(3/2 + N)T - 175	Maximum
t _{RAE}	(1/2)T - 10	(1/2)T — 10	(1/2)T — 33	Minimum
t _{CA}	(1/2)T - 40	(1/2)T — 40	(1/2)T - 53	Minimum
t _{DW}	(3/2 + N)T - 60	(3/2 + N)T - 70	(3/2 + N)T - 110	Minimum
t _{WD}	(1/2)T - 60	(1/2)T 40	(1/2)T - 53	Minimum
tcc	(3/2 + N)T - 80	(3/2 + N)T - 70	(3/2 + N)T - 100	Minimum
t _{CL}	(1/2)T - 110	(1/2)T — 75	(1/2)T - 83	Minimum
tARY	(3/2)T - 260	(3/2)T - 200	(3/2)T - 210	Maximum
tHACK	(1/2)T - 50	(1/2)T — 60	(1/2)T - 83	Minimum
t _{HABF}	(1/2)T + 50	(1/2)T + 50	(1/2)T + 67	Maximum
t _{HABE}	(1/2)T + 50	(1/2)T + 50	(1/2)T + 67	Maximum
tAC	(2/2)T — 50	(2/2)T — 85	(2/2)T - 97	Minimum
t ₁	(1/2)T — 80	(1/2)T - 60	(1/2)T - 63	Minimum
t ₂	(1/2)T - 40	(1/2)T — 30	(1/2)T - 33	Minimum
t _{RV}	(3/2)T - 80	(3/2)T - 80	(3/2)T - 90	Minimum
t _{LDR}	(4/2 + N)T - 180	(4/2)T - 130	(4/2)T — 159	Maximum

NOTE:

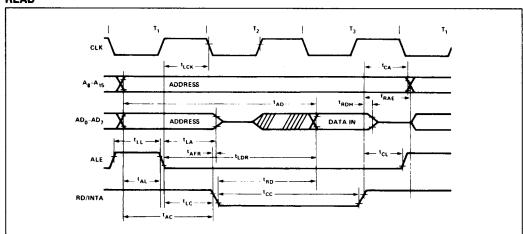
N is equal to the total WAIT states. $T = t_{CYC}$.

WAVEFORMS

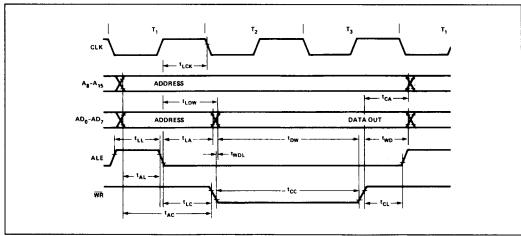
CLOCK



READ

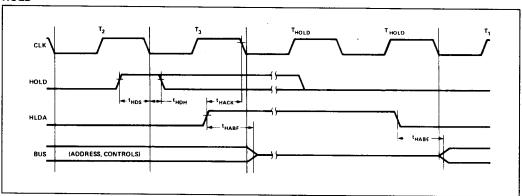


WRITE

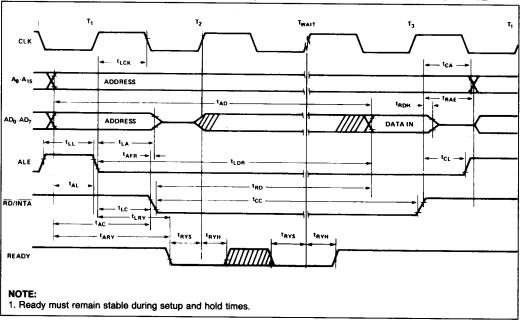


WAVEFORMS (Continued)

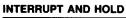




READ OPERATION WITH WAIT CYCLE (TYPICAL)—SAME READY TIMING APPLIES TO WRITE



WAVEFORMS (Continued)



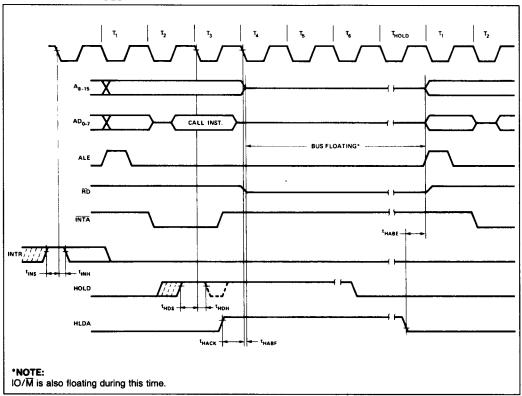


Table 6. Instruction Set Summary

Mnemonic			nstr					_	Operations				
	יע		D ₅			D ₂	D ₁	D ₀	Description				
MOVE, LOAD AND STORE													
MOVr1 r2	0	1	D 	D 	D	s	s 	_s 	Move register to register				
MOV M.r	0	1	1	1	0	s	S	s	Move register to memory				
MOV r.M	0	1	D	D	D	1	1	0	Move memory to register				
MVIr	0	0	D	D	D	1	1	0	Move immediate register				
MVIM	0	0	1	1	0	1	1	0	Move immediate memory				
LXIB	0	0	0	0	0	0	0	1	Load immediate register Pair B & C				
LXID	0	0	0	1	0	0	0	1	Load immediate register Pair D & E				
LXI H	0	0	1	0	0	0	0	1	Load immediate register Pair H & L				
STAX B	0	0	0	0	0	0	1	0	Store A indirect				
STAX D	0	0	0	1	0	0	1	0	Store A indirect				
LDAX B	0	0	1	0	1	0	1	0	Load A indirect				
LDAX D	0	0	0	1	1	0	1	0	Load A indirect				
STA	0	0	1	1	0	0	1	0	Store A direct				
LDA	0	0	1	1	1	0	1	0	Load A direct				
SHLD	0	0	1	0	0	0	1	0	Store H & L direct				
LHLD	0	0	1	0	1	0	1	0	Load H & L direct				
XCHG	1	1	1	0	1	0	1	1	Exchange D & E, H & L Registers				
STACK OP	S												
PUSH B	1	1	0	0	0	1	0	1	Push register Pair B & C on stack				
PUSH D	1	1	0	1	0	1	0	1	Push register Pair D & E on stack				
PUSH H	1	1	1	0	0	1	0	1	Push register Pair H & L on stack				
PUSH PSW	1	1	1	1	0	1	0	1	Push A and Flags on stack				
POP B	1	1	0	0	0	0	0	1	Pop register Pair B & C off stack				
POP D	1	1	0	1	0	0	0	1	Pop register Pair D & E off stack				
POP H	1	1	1	0	0	0	0		Pop register Pair H & L off stack				

Mnemonic						Co			Operations				
STACK OF					_	D ₂	D ₁	D ₀	Description				
	STACK OPS (Continued) POP PSW 1 1 1 1 0 0 0 1 Pop A and Flags												
POP PSW	1	1	1	1	0	0	0	1	Pop A and Flags off stack				
XTHL	1	1	1	0	0	0	1	1	Exchange top of stack, H & L				
SPHL	1	1	1	1	1	0	0	1	H & L to stack pointer				
LXI SP	0	0	1	1	0	0	0	1	Load immediate stack pointer				
INX SP	0	0	1	1	0	0	1	1	Increment stack pointer				
DCX SP	0	0	1	1	1	0	1	1	Decrement stack pointer				
JUMP	The state of the s												
JMP	1	1	0	0	0	0	1	1	Jump unconditional				
JC	1	1	0	1	1	0	1	0	Jump on carry				
JNC	1	1	0	1	0	0	1	0	Jump on no carry				
JZ	1	1	0	0	1	0	1	0	Jump on zero				
JNZ	1	1	0	0	0	0	1	0	Jump on no zero				
JP	1	1	1	1	0	0	1	0	Jump on positive				
JM	1	1	1	1	1	0	1	0	Jump on minus				
JPE	1	1	1	0	1	0	1	0	Jump on parity even				
JPO	1	1	1	0	0	0	1	0	Jump on parity odd				
PCHL	1	1	1	0	1	0	0	1	H & L to program counter				
CALL													
CALL	1	1	0	0	1	1	0	1	Call unconditional				
CC	1	1	0	1	1	1	0	0	Call on carry				
CNC	1	1	0	1	0	1	0	0	Call on no carry				
CZ	1	1	0	0	1	1	0	0	Call on zero				
CNZ	1	1	0	0	0	1	0	0	Call on no zero				
СР	1	1	1	1	0	1	0	0	Call on positive				
СМ	1	1	1	1	1	1	0	0	Call on minus				
CPE	1	1	1	0	1	1	0	0	Call on parity even				
СРО	1	1	1	0	0	1	0	0	Call on parity odd				
RETURN													
RET	1	1	0	0	1	0	0	1	Return				
RC	1	1	0	1	1	0	0	0	Return on carry				
RNC	1	1	0	1	0	0	0	\neg	Return on no carry				
RZ	1	1	0	0	1	0	0	0	Return on zero				

Table 6. Instruction Set Summary (Continued)

Mnemonic	D ₇					Coc D ₂		D ₀	Operations Description			
RETURN (Con	tinu	ed)									
RNZ	1	1	0	0	0	0	0	0	Return on no zero			
RP	1	1	1	1	0	0	0	0	Return on positive			
RM	1	1	1	1	1	0	0	0	Return on minus			
RPE	1	1	1	0	1	0	0	0	Return on parity even			
RPO	1	1	1	0	0	0	0	0	Return on parity odd			
RESTART												
RST	1	1	Α	Α	Α	1	1	1	Restart			
INPUT/OU	INPUT/OUTPUT											
ŧΝ	1	1	0	1	1	0	1	1	Input			
OUT	1	1	0	1	0	0	1	1	Output			
INCREMENT AND DECREMENT												
INR r	0	0	D	D	D	1	0	0	Increment register			
DCR r	0	0	D	D	D	1	0	1	Decrement register			
INR M	0	0	1	1	0	1	0	0	Increment memory			
DCR M	0	0	1	1	0	1	0	1	Decrement memory			
INX B	0	0	0	0	0	0	1	1	Increment B & C registers			
INX D	0	0	0	1	0	0	1	1	Increment D & E registers			
INX H	0	0	1	0	0	0	1	1	Increment H & L registers			
DCX B	0	0	0	0	1	0	1	1	Decrement B & C			
DCX D	0	0	0	1	1	0	1	1	Decrement D & E			
DCX H	0	0	1	0	1	0	1	1	Decrement H & L			
ADD												
ADD r	1	0	0	0	0	s	s	s	Add register to A			
ADC r	1	0	0	0	1	s	S	s	Add register to A with carry			
ADD M	1	0	С	0	0	1	1	0	Add memory to A			
ADC M	1	0	0	0	1	1	1	0	Add memory to A with carry			
ADI	1	1	0	0	0	1	1	0	Add immediate to A			
ACI	1	1	0	0	1	1	1	0	Add immediate to A with carry			
DAD B	0	0	0	0	1	0	0	1	Add B & C to H & L			

Summary .	(Continued)										
Mnemonic	D ₇	in D ₆	stru D ₅	ucti D ₄	on D ₃	Co D ₂	de D ₁	Do	Operations Description		
ADD (Conti	nue	ed)									
DAD D	0	0	0	1	1	0	0	1	Add D & E to H & L		
DAD H	0	0	1	0	1	0	0	1	Add H & L to H & L		
DAD SP	0	0	1	1	1	0	0	1	Add stack pointer to H & L		
SUBTRAC	T										
SUB r	1	0	0	1	0	s	s	s	Subtract register from A		
SBB r	1	0	0	1	1	s	s	S	Subtract register from A with borrow		
SUB M	1	0	0	1	0	1	1	0	Subtract memory from A		
SBB M	1	0	0	1	1	1	1	0	Subtract memory from A with borrow		
SUI	1	1	0	1	0	1	1	0	Subtract immediate from A		
SBI	1	1	0	1	1	1	1	0	Subtract immediate from A with borrow		
LOGICAL											
ANA r	1	0	1	0	0	s	s	s	And register with A		
XRA r	1	0	1	0	1	S	s	s	Exclusive OR register with A		
ORA r	1	0	1	1	0	s	s	s	OR register with A		
CMP r	1	0	1	1	1	s	S	s	Compare register with A		
ANA M	1	0	1	0	0	1	1	0	And memory with A		
XRA M	1	0	1	0	1	1	1	0	Exclusive OR memory with A		
ORA M	1	0	1	1	0	1	1	0	OR memory with A		
CMP M	1	0	1	1	1	1	1	0	Compare memory with A		
ANI	1	1	1	0	0	1	1	0	And immediate with A		
XRI	1	1	1	0	1	1	1	0	Exclusive OR immediate with A		
ORI	1	1	1	1	0	1	1	0	OR immediate with A		
CPI	1	1	1	1	1	1	1	0	Compare immediate with A		

Table 6. Instruction Set Summary (Continued)

Mnemonic	D ₇		str D ₅					Do	Operations Description
ROTATE				7				-0	
RLC	0	0	0	0	0	1	1	1	Rotate A left
RRC	0	0	0	0	1	1	1	1	Rotate A right
RAL	0	0	0	1	0	1	1	1	Rotate A left through carry
RAR	0	0	0	1	1	1	1	1	Rotate A right through carry
SPECIALS									
СМА	0	0	1	0	1	1	1	1	Complement A
STC	0	0	1	1	0	1	1	1	Set carry
СМС	0	0	1	1	1	1	1	1	Complement carry
DAA	0	0	1	0	0	1	1	1	Decimal adjust A

Mnemonic	D ₇		nstr D ₅		-		-	Do	Operations Description		
CONTROL								<u>*</u>	· · · · · · · · · · · · · · · · · · ·		
EI	1	1	1	1	1	0	1	1	Enable Interrupts		
DI	1	1	1	1	0	0	1	1	Disable Interrupt		
NOP	0	0	0	0	0	0	0	0	No-operation		
HLT	0	1	1	1	0	1	1	0	Halt		
NEW 8085/	NEW 8085AH INSTRUCTIONS										
RIM	0	0	1	0	0	0	0	0	Read Interrupt Mask		
SIM	0	0	1	1	0	0	0	0	Set Interrupt Mask		

NOTES:

- DDS or SSS: B 000, C 001, D 010, E011, H 100, L101, Memory 110, A 111.
 Two possible cycle times (6/12) indicate instruction cycles dependent on condition flags.

Rochester Electronics guarantees performance of its semiconductor products to the original OEM specifications. "Typical" values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing. Rochester Electronics reserves the right to make changes without further notice to any specification herein.